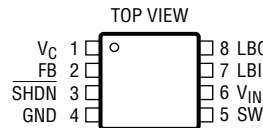
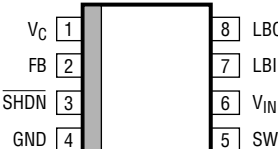


ABSOLUTE MAXIMUM RATINGS (Note 1)

V_{IN} , LBO Voltage	12V	Junction Temperature	125°C
SW Voltage	-0.4V to 30V	Operating Temperature Range (Note 2)	
FB Voltage	$V_{IN} + 0.3V$	LT1949EMS8	-40°C to 85°C
V_C Voltage	2V	LT1949ES8/LT1949IS8	-40°C to 85°C
LBI Voltage	$0V \leq V_{LBI} \leq 1V$	Storage Temperature	-65°C to 150°C
SHDN Voltage	6V	Lead Temperature (Soldering, 10sec)	300°C

PACKAGE/ORDER INFORMATION

 MS8 PACKAGE 8-LEAD PLASTIC MSOP $T_{JMAX} = 125^{\circ}C$, $\theta_{JA} = 120^{\circ}C/W$	ORDER PART NUMBER	 S8 PACKAGE 8-LEAD PLASTIC SO $T_{JMAX} = 125^{\circ}C$, $\theta_{JA} = 120^{\circ}C/W$	ORDER PART NUMBER
	LT1949EMS8		LT1949ES8 LT1949IS8
	MS8 PART MARKING		S8 PART MARKING
	LTJC		1949E 1949I

Consult factory for Military grade parts.

ELECTRICAL CHARACTERISTICS

The ● denotes specifications which apply over the full operating temperature range, otherwise specifications are $T_A = 25^{\circ}C$. $V_{IN} = 2V$, $V_{SHDN} = 2V$ unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
I _Q	Quiescent Current	V _{SHDN} = 0V	● ●		4.5 25	7.5 40	mA μA
V _{FB}	Feedback Voltage		● ●	1.22 1.20	1.24 1.24	1.26 1.26	V V
I _B	FB Pin Bias Current (Note 3)		●		12	80	nA
	Input Voltage Range		●	1.7		12	V
g _m	Error Amp Transconductance	ΔI = 5μA	●	70	140	240	μmhos
A _V	Error Amp Voltage Gain				700		V/V
	Maximum Duty Cycle		●	80	85		%
	Switch Current Limit (Note 4)	V _{IN} = 2.5V, Duty Cycle = 30%	●	1	1.13	1.5	A
		V _{IN} = 2.5V, Duty Cycle = 30%	●	0.95		1.5	A
f _{osc}	Switching Frequency		●	500	600	750	kHz
	Shutdown Pin Current	V _{SHDN} = V _{IN}	●		0.015	0.1	μA
		V _{SHDN} = 0V	●		−2.3	−7	μA
	LBI Threshold Voltage		● ●	190 180	200 200	210 220	mV mV
	LBO Output Low	I _{SINK} = 10μA	●		0.15	0.25	V
	LBO Leakage Current	V _{LBI} = 250mV, V _{LBO} = 5V	●		0.02	0.1	μA
	LBI Input Bias Current (Note 5)	V _{LBI} = 150mV	●		5	60	nA
	Low-Battery Detector Gain	1MΩ Pull-Up			2000		V/V
	Switch Leakage Current	V _{SW} = 5V	●		0.01	3	μA

ELECTRICAL CHARACTERISTICS

The ● denotes specifications which apply over the full operating temperature range, otherwise specifications are $T_A = 25^\circ\text{C}$. $V_{IN} = 2\text{V}$, $V_{SHDN} = 2\text{V}$ unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
	Switch V_{CESAT}	$I_{SW} = 800\text{mA}$ $I_{SW} = 500\text{mA}$		410	400	mV mV
	Reference Line Regulation	$1.8\text{V} \leq V_{IN} \leq 12\text{V}$		0.08	0.15	%/V
	$\overline{\text{SHDN}}$ Input Voltage High		1.4		6	V
	$\overline{\text{SHDN}}$ Input Voltage Low				0.4	V

Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

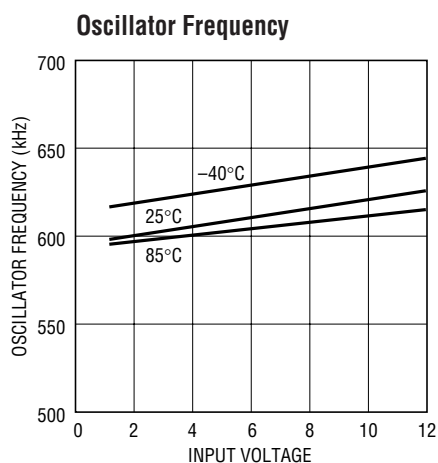
Note 2: The LT1949E is guaranteed to meet performance specifications from 0°C to 70°C . Specifications over the -40°C to 85°C operating temperature range are assured by design, characterization and correlation with statistical process controls.

Note 3: Bias current flows into FB pin.

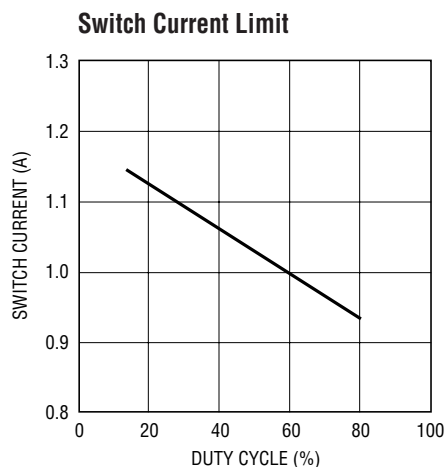
Note 4: Switch current limit guaranteed by design and/or correlation to static tests. Duty cycle affects current limit due to ramp generator.

Note 5: Bias current flows out of LBI pin.

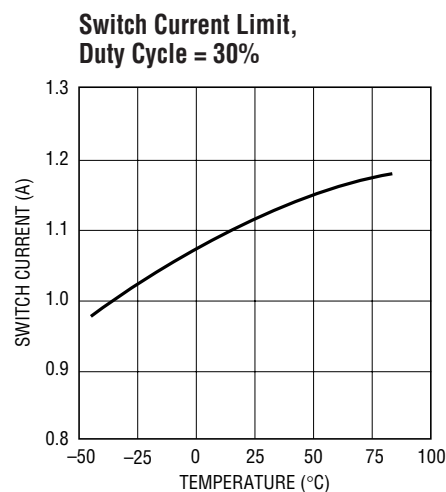
TYPICAL PERFORMANCE CHARACTERISTICS



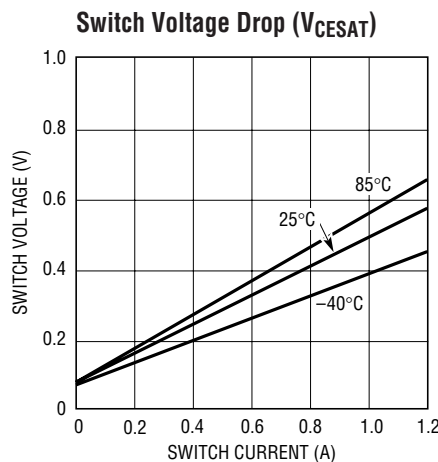
1949 G01



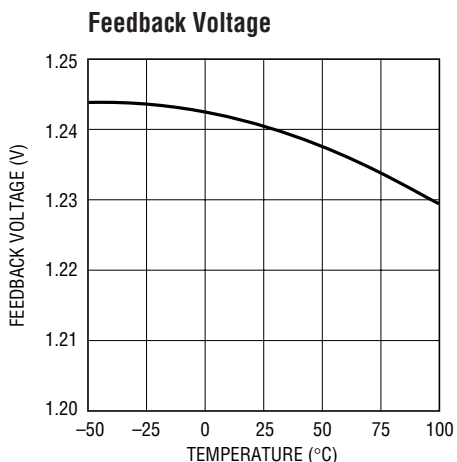
1949 G02



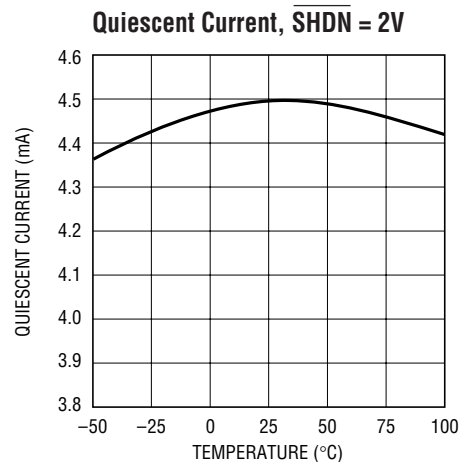
1949 G03



1949 G04

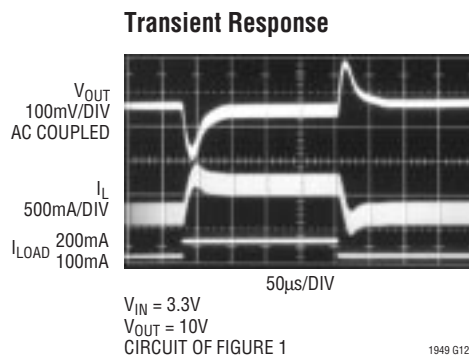
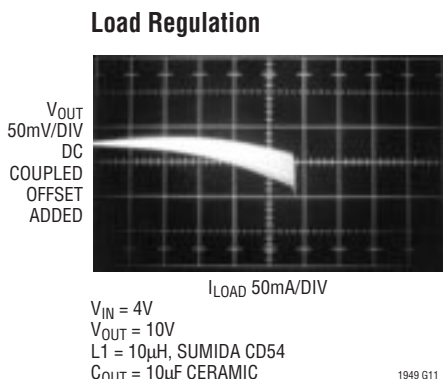
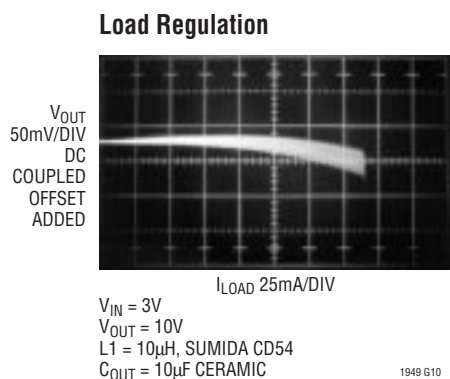
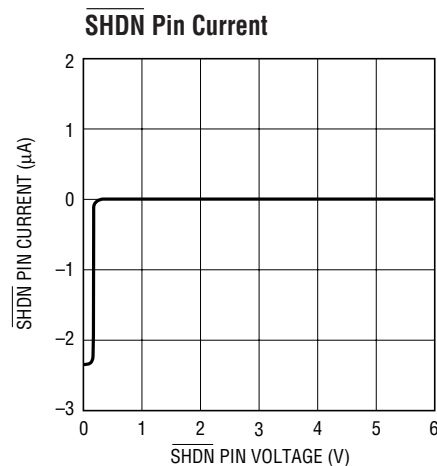
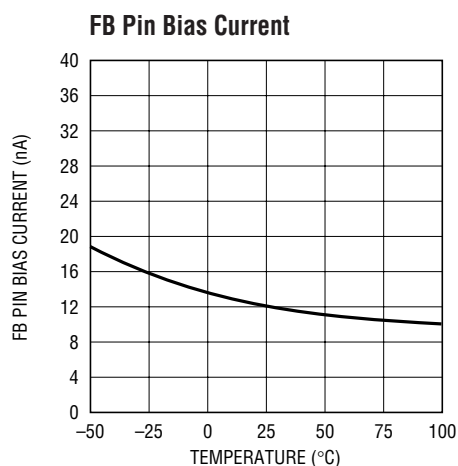
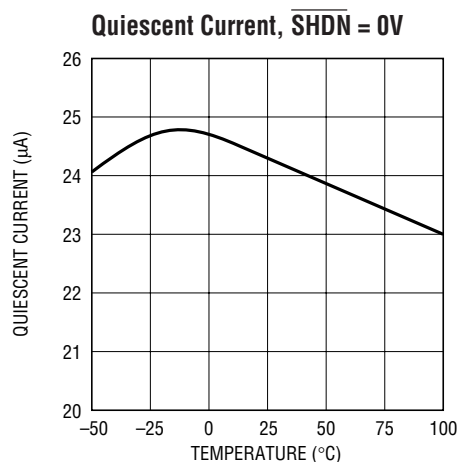


1949 G05



1949 G06

TYPICAL PERFORMANCE CHARACTERISTICS



PIN FUNCTIONS

V_C (Pin 1): Compensation Pin for Error Amplifier. Connect a series RC network from this pin to ground. Typical values for compensation are a 68k/330pF combination when using ceramic output capacitors. Minimize trace area at V_C .

FB (Pin 2): Feedback Pin. Reference voltage is 1.24V. Connect resistor divider tap here. Minimize trace area at FB. Set V_{OUT} according to: $V_{\text{OUT}} = 1.24\text{V}(1 + R1/R2)$.

$\overline{\text{SHDN}}$ (Pin 3): Shutdown. Pull this pin low for shutdown mode (only the low-battery detector remains active). Leave this pin floating or tie to a voltage between 1.4V and 6V to enable the device. $\overline{\text{SHDN}}$ pin is logic level and need only meet the logic specification (1.4V for high, 0.4V for low).

GND (Pin 4): Ground. Connect directly to local ground plane.

SW (Pin 5): Switch Pin. Connect inductor/diode here. Minimize trace area at this pin to keep EMI down.

V_{IN} (Pin 6): Supply Pin. Must be bypassed close to the pin.

LBI (Pin 7): Low-Battery Detector Input. 200mV reference. Voltage on LBI must stay between ground and 700mV. Low-battery detector remains active in shutdown mode.

LBO (Pin 8): Low-Battery Detector Output. Open collector, can sink 10µA. A 1MΩ pull-up is recommended.

OPERATION

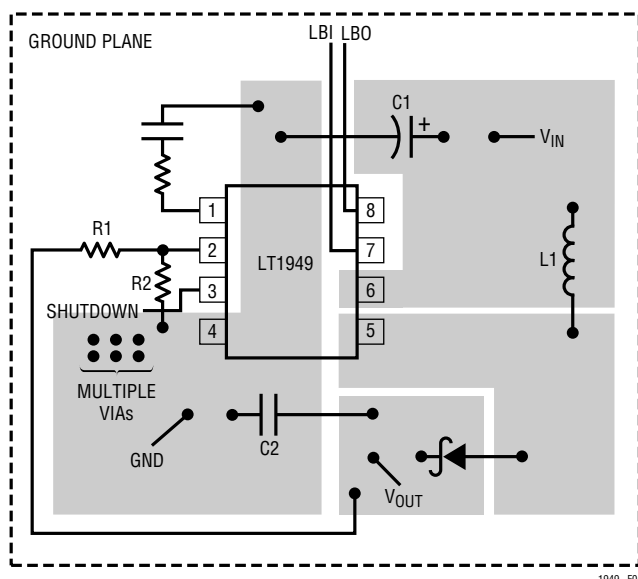


Figure 4. Recommended Component Placement for Boost Converter. Note Direct High Current Paths Using Wide PC Traces. Minimize Trace Area at Pin 1 (V_C) and Pin 2 (FB). Use Multiple Vias to Tie Pin 4 Copper to Ground Plane. Use Vias at One Location Only to Avoid Introducing Switching Currents into the Ground Plane

APPLICATIONS INFORMATION

Low-Battery Detector

The LT1949's low-battery detector is a simple PNP input gain stage with an open collector NPN output. The negative input of the gain stage is tied internally to a 200mV $\pm 5\%$ reference. The positive input is the LBI pin. Arrangement as a low-battery detector is straightforward.

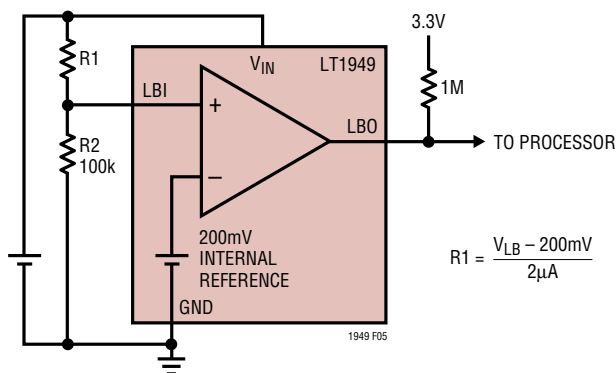


Figure 5. Setting Low-Battery Detector Trip Point

Figure 5 details hookup. R1 and R2 need only be low enough in value so that the bias current of the LBI pin doesn't cause large errors. For R2, 100k is adequate. The 200mV reference can also be accessed as shown in Figure 6. The low-battery detector remains active in shutdown.

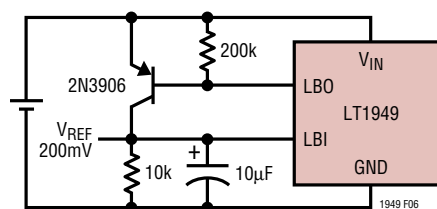
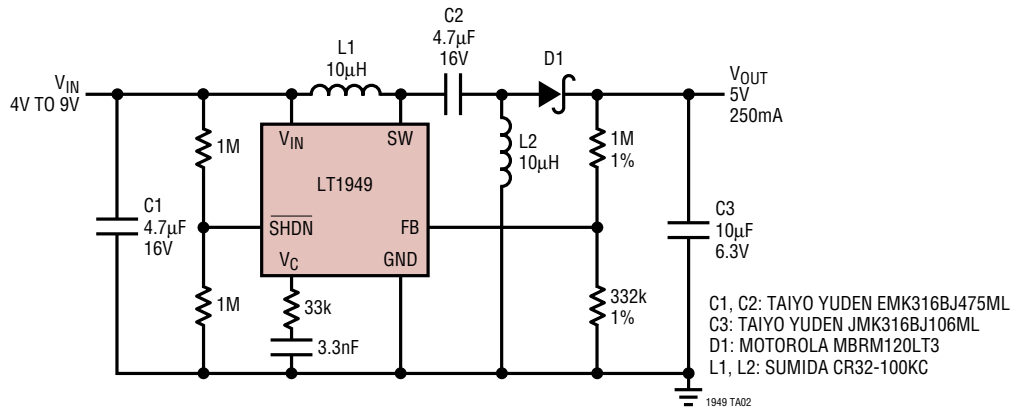


Figure 6. Accessing 200mV Reference

TYPICAL APPLICATION

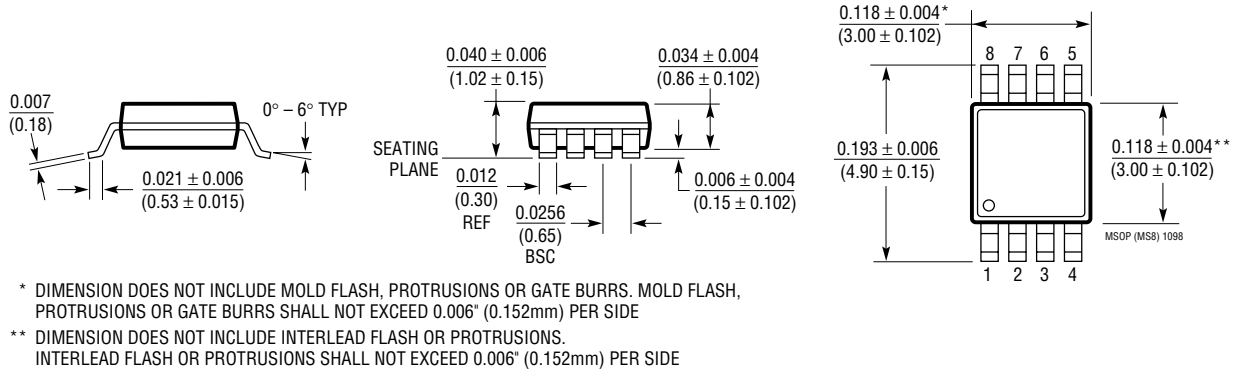
4 Cell to 5V SEPIC Converter



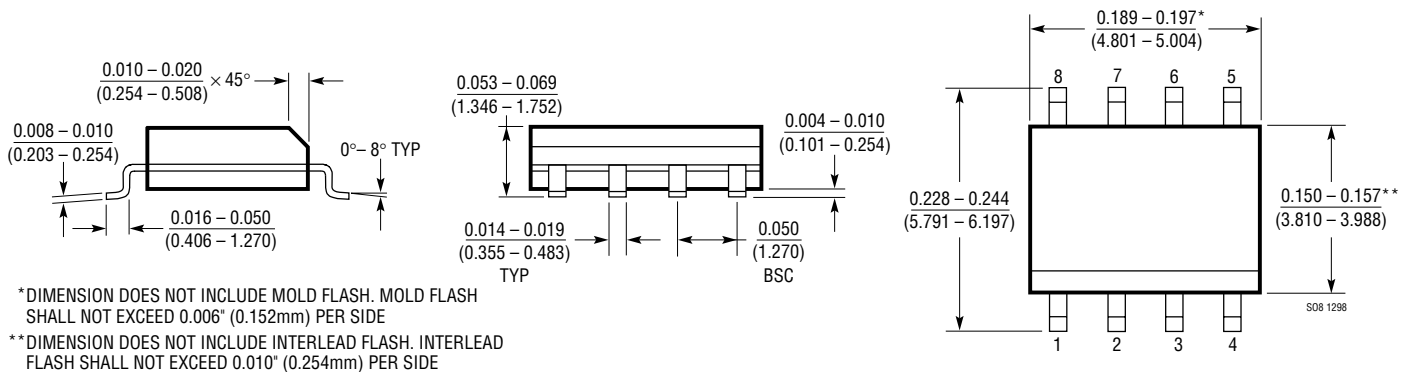
PACKAGE DESCRIPTION

Dimensions in inches (millimeters) unless otherwise noted.

MS8 Package 8-Lead Plastic MSOP (LTC DWG # 05-08-1660)

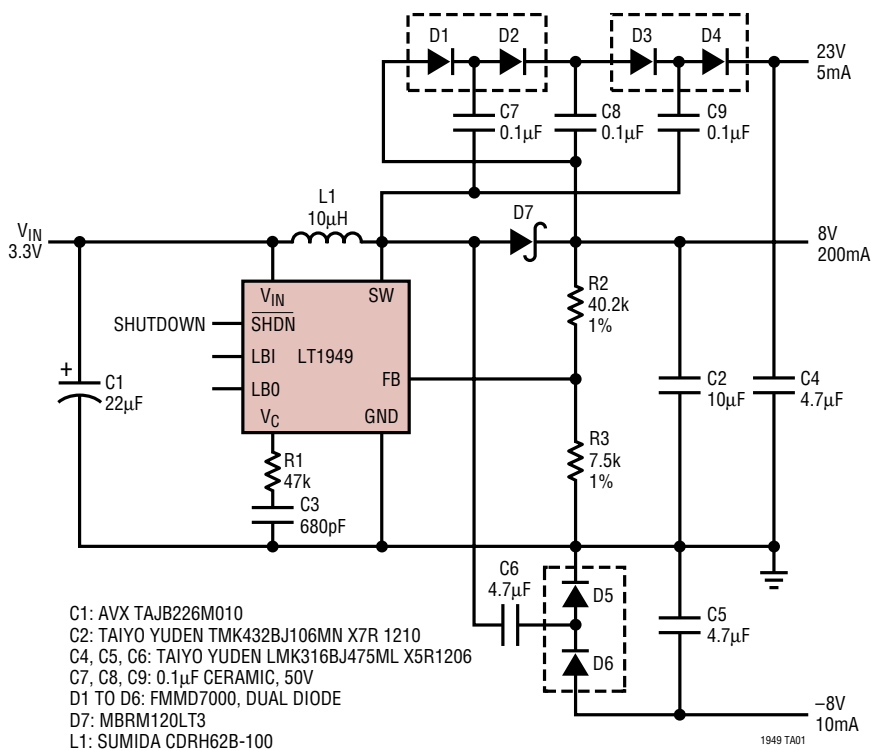


S8 Package 8-Lead Plastic Small Outline (Narrow 0.150) (LTC DWG # 05-08-1610)



TYPICAL APPLICATION

Low Profile Triple Output LCD Bias Generator



C1: AVX TAJB226M010
C2: TAIYO YUDEN TMK432BJ106MN X7R 1210
C4, C5, C6: TAIYO YUDEN LMK316BJ475ML X5R1206
C7, C8, C9: 0.1µF CERAMIC, 50V
D1 TO D6: FMMD7000, DUAL DIODE
D7: MBRM120LT3
L1: SUMIDA CDRH62B-100

RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LT1054	High Power Regulated Charge Pump	Up to 100mA Output with No Inductors
LT1302	High Output Current Micropower DC/DC Converter	5V/600mA from 2V, 2A Internal Switch, 200µA I _Q
LT1304	2-Cell Micropower DC/DC Converter	Low-Battery Detector Active in Shutdown
LT1307B	Single Cell Micropower 600kHz PWM DC/DC Converter	3.3V at 75mA from 1 Cell, MSOP Package
LT1308B	2A 600kHz PWM DC/DC Converter	TSSOP Package
LT1317B	Micropower, 600kHz PWM DC/DC Converter	2 Cells to 3.3V at 200mA, MSOP Package
LTC [®] 1516	2-Cell to 5V Regulated Charge Pump	12µA I _Q , No Inductors, 5V at 50mA from 3V Input
LT1613	Single Cell 1.4MHz PWM DC/DC Converter	3.3V to 5V at 200mA, SOT-23 Package
LTC1682	Doubler Charge Pump with Low Noise Linear Regulator	3.3V and 5V Outputs with 60µV _{RMS} Noise, Up to 80mA Output
LTC1754	Micropower 3.3V/5V Charge Pump with Shutdown	Up to 50mA Output, I _Q = 13µA, SOT-23 Package